

100V PNP HIGH VOLTAGE TRANSISTOR IN SOT23

Features

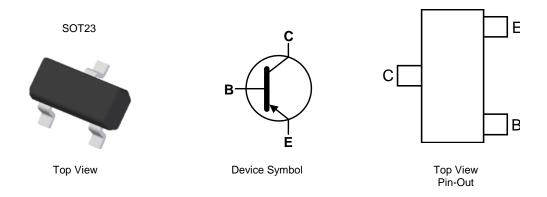
- BV_{CEO} > -100V
- I_C = -1A High Continuous Collector Current
- I_{CM} = -2A Peak Pulse Current
- Low Saturation Voltage
- Excellent h_{FE} Characteristics up to I_C = -1A
- Complementary NPN Type: FMMT493
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: SOT23 (Type DN)
- Package Material: Molded Plastic, "Green" Molding Compound UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 <a>®3
- Weight 0.008 grams (Approximate)

Applications

- High-Side Drivers
- Load Disconnect Switches
- Motor Drives



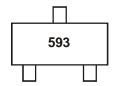
Ordering Information (Note 4)

Part Number	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
FMMT593TA	Standard	593	7	8	3000
FMMT593TC	Standard	593	13	8	10,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



593 = Product Type Marking Code



Absolute Maximum Ratings (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-120	V
Collector-Emitter Voltage	V _{CEO}	-100	V
Emitter-Base Voltage	V_{EBO}	-7	V
Continuous Collector Current	Ic	-1	Α
Peak Pulse Current	Ісм	-2	А
Continuous Base Current	I _B	-200	mA

Thermal Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Power Dissipation	(Note 5)	P _D	500	mW
Thermal Resistance, Junction to Ambient	(Note 5)	R _{OJA}	250	°C/W
Thermal Resistance, Junction to Lead	(Note 6)	R _{OJL}	197	°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C

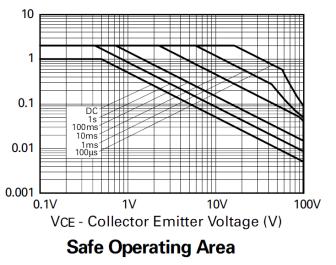
Notes:

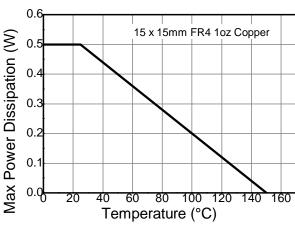
^{5.} For a device surface mounted on 15mm x 15mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in a steady-state condition.

6. Thermal resistance from junction to solder-point (at the end of the collector lead).

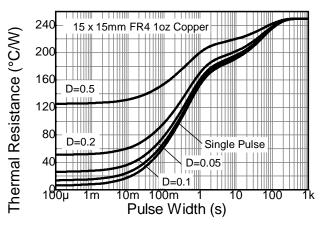


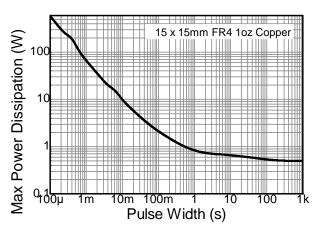
Thermal Characteristics and Derating Information





Derating Curve





Transient Thermal Impedance

Pulse Power Dissipation



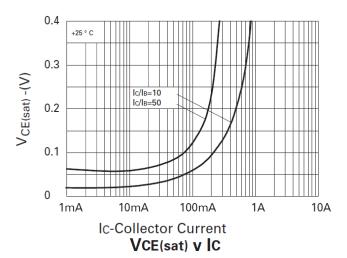
Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

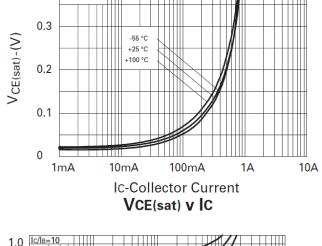
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	-120	_	_	V	I _C = -100μA
Collector-Emitter Breakdown Voltage (Note 7)	BV _{CEO}	-100	_	_	V	I _C = -1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	-7	_	_	V	I _E = -100μA
Collector Cutoff Current	I _{CBO}	_	_	-100	nA	V _{CB} = -100V
Emitter Cutoff Current	I _{EBO}	_	_	-100	nA	V _{EB} = -5.6V
Collector-Emitter Cut-Off Current	I _{CES}	_	_	-100	nA	V _{CES} = -100V
Static Forward Current Transfer Ratio (Note 7)	h _{FE}	100 100 100 50	_	— 300 —	_	$\begin{split} I_{C} &= -1 \text{mA}, \ V_{CE} = -5 \text{V} \\ I_{C} &= -250 \text{mA}, \ V_{CE} = -5 \text{V} \\ I_{C} &= -500 \text{mA}, \ V_{CE} = -5 \text{V} \\ I_{C} &= -1 \text{A}, \ V_{CE} = -5 \text{V} \end{split}$
Collector-Emitter Saturation Voltage (Note 7)	V _{CE(sat)}	_	_	-200 -300	mV	$I_C = -250$ mA, $I_B = -25$ mA $I_C = -500$ mA, $I_B = -50$ mA
Base-Emitter Saturation Voltage (Note 7)	V _{BE(sat)}	_	_	-1.1	V	$I_C = -500 \text{mA}, I_B = -50 \text{mA}$
Base-Emitter Turn-On Voltage (Note 7)	V _{BE(on)}	_	_	-1.0	V	$I_C = -1mA, V_{CE} = -5V$
Transition Frequency	f _T	50	_	_	MHz	V _{CE} = -10V, I _C = -50mA, f = 100MHz
Output Capacitance	C _{obo}	_	_	10	pF	V _{CB} = -20V, f = 1MHz

Notes: 7. Measured under pulsed conditions. Pulse width ≤ 300µs. Duty cycle ≤ 2%.



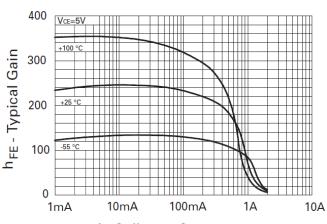
Typical Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.)

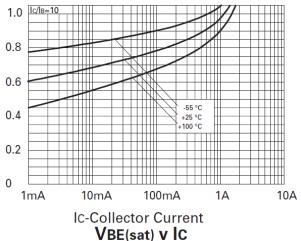




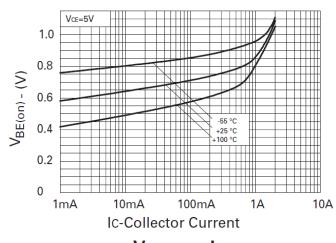
0.4

IA/IB=10





Ic-Collector Current **hFE V IC**



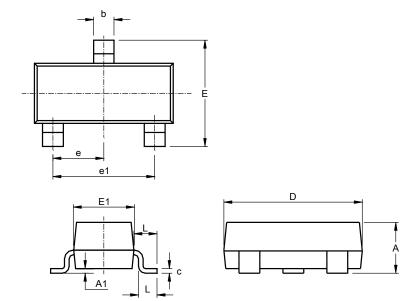
VBE(on) v Ic



Package Outline Dimensions

 $Please see \ http://www.diodes.com/package-outlines.html \ for \ the \ latest \ version.$

SOT23 (Type DN)

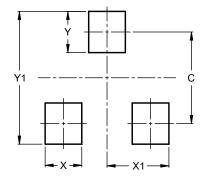


S	SOT23 (Type DN)					
Dim	Min	Max	Тур			
Α	0.89	1.12	1.00			
A1	0.01	0.10	0.05			
b	0.30	0.51	0.45			
С	0.08	0.20	0.10			
D	2.80	3.04	3.00			
Е	2.10	2.64	2.42			
E1	1.20	1.40	1.37			
е	0.95 REF					
e1	1.90 REF					
L	0.25	0.60	0.30			
L1	0.45	0.62	0.54			
All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23 (Type DN)



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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